

High performance low voltage NPN transistor

Features

- Very low collector to emitter saturation voltage
- DC current gain, h_{FE} > 100
- 3 A continuous collector current
- 40 V breakdown voltage V_{(BR)CER}

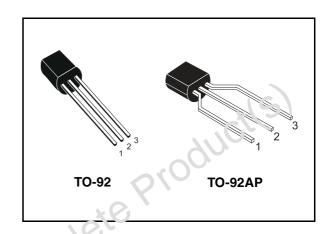
Applications

- Power management in portable equipment
- Voltage regulation in bias supply circuits
- Switching regulator in battery charger applications
- Heavy load driver

Description

)psolete

The device is manufactured in low voltage NFN planar technology by using a "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage.



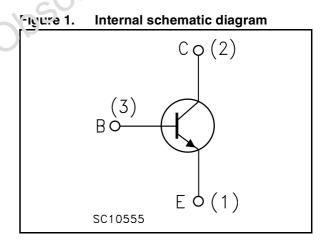


Table 1. Device summary

Order code	Marking	Package	Packaging
STX690A	X690A	TO-92	Bulk
STX690A-AP	X690A	X690A TO-92 AP	

Electrical ratings STX690A

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	40	V
V _{CER}	Collector-emitter voltage ($R_{BE} = 47 \Omega$)	40	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	30	V
V _{EBO}	Emitter-base voltage ($I_C = 0$)	5	V
I _C	Collector current	3 (9	Α
I _{CM}	Collector peak current (t _P < 5 ms)	6	Α
P _{tot}	Total dissipation at T _{amb} = 25 °C	77.9	W
T _{stg}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Table 3. Thermal data

	Symbol	Paramete:		Value	Unit	
	R _{thj-amb}	Thermal resistance junction-and	max	139	°C/W	
Obsole	te P	roduci(s)				

2 Electrical characteristics

 $(T_{case} = 25 \, ^{\circ}C \text{ unless otherwise specified})$

Table 4. Electrical characteristics

	Symbol	Parameter	Test co	nditions	Min.	Тур.	Max.	Unit
	Ісво	Collector cut-off current (I _E = 0)	$V_{CB} = 30 \text{ V}$ $V_{CB} = 30 \text{ V}$;	T _C = 100 °C			10 100	μ Α μ Α
	I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 4 V				10	μΑ
	V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = 10 mA		30	40		V
	V _{(BR)CER} (1)	Collector-emitter breakdown voltage (R _{BE} = 47 Ω)	I _C = 10 mA	*6	40			V
	V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	Ι _C = 100 μΑ	Ver	40			V
	V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	:_ = 100 μA		5			V
		.(6)	I _C = 0.5 A	$I_B = 5 \text{ mA}$		0.08	0.15	٧
	V (1)	Callyday	$I_C = 1.2 A$ $I_C = 2 A$	$I_B = 20 \text{ mA}$ $I_B = 20 \text{ mA}$		0.1 0.175	0.22 0.35	V V
	V _{CE(sat)} (1)	Collector emitter	$I_C = 3 A$	$I_B = 20 \text{ m/s}$ $I_B = 100 \text{ mA}$		0.173	0.4	٧
	20	0	I _C = 3 A	I _B = 100 mA				
			T _C = 100 °C			0.3		٧
9/6	V _{BE(sat)} (1)	Base-emitter saturation voltage	I _C = 1 A	I _B = 10 mA		0.8	1	٧
	V _{BE(on)} (1)	Base-emitter on voltage	I _C = 1 A	V _{CE} = 2 V		0.8	1	V
			I _C = 10 mA	V _{CE} = 2 V	100	200	400	
			$I_{C} = 500 \text{ mA}$	$V_{CE} = 2 V$	100	200	400	
	h _{FE} ⁽¹⁾	DC current gain	I _C = 1 A	$V_{CE} = 2 V$	100			
			I _C = 2 A	$V_{CE} = 1 V$	100	160		
			$I_C = 3 A$	$V_{CE} = 1 V$	90	130		

3/10

Electrical characteristics STX690A

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
f _t	Transition frequency	$I_C = 50 \text{ mA}$ $V_{CE} = 5 \text{ V}$ $f = 50 \text{ MHz}$		100		MHz
t _d t _r	Resistive load Delay time Rise time	$I_C = 3 A$ $V_{CC} = 20 V$ $I_{B1} = -I_{B2} = 60 \text{ mA}$		50 120		ns ns

see Figure 8

Table 4. Electrical characteristics (continued)

Storage time

Fall time

2.1 Electrical characteristics (curves)

Figure 2. DC current gain

Figure 3. DC current vain

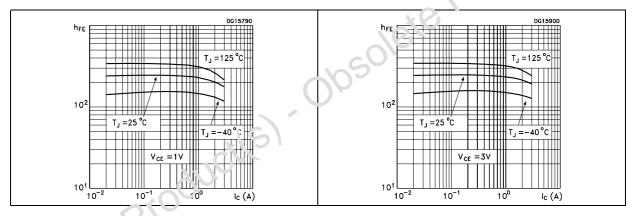


Figure 4. Collector-emitter saturation

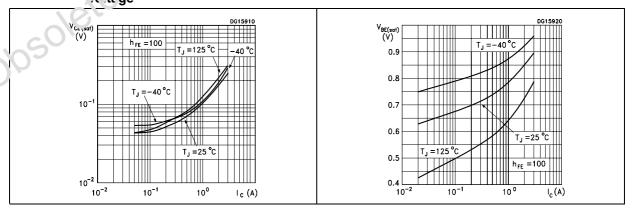
Figure 5. Base-emitter saturation voltage

465

80

ns

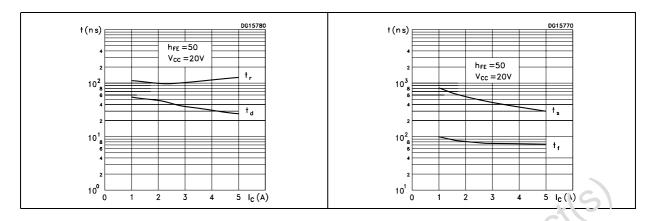
ns



^{1.} Pulse duration = 300 µs, duty cycle ≤1.5%

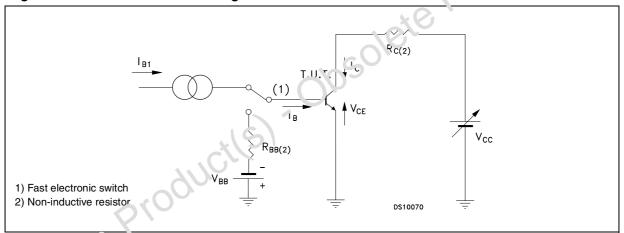
Figure 6. Switching time resistive load

Figure 7. Switching time resistive load



2.2 Test circuit

Figure 8. Resistive load switching test circuit



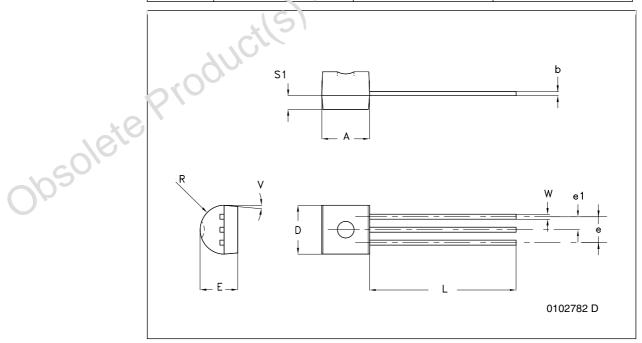
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and products status are available at: www.st.com. ECOPACK is an ST trademark.

Obsolete Product(s). Obsolete Product(s)

TO-92 bulk shipment mechanical data

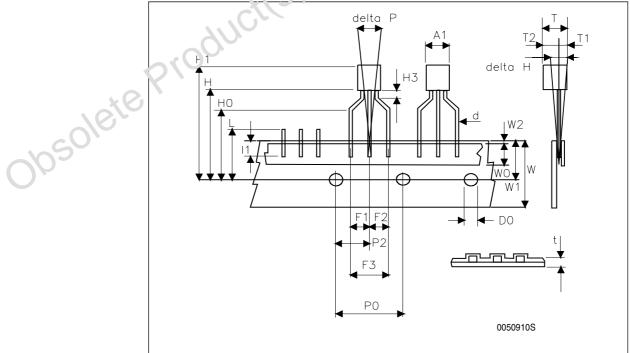
DIM.	mm.				
DIW.	MIN.	ТҮР	MAX.		
А	4.32		4.95		
b	0.36		0.51		
D	4.45		4.95		
E	3.30		5.54		
е	2.41		2.67		
e1	1.14	Q	1.40		
L	12.70	×8,	15.49		
R	2.16	16,	2.41		
S1	0.92	20,	1.52		
W	0.41	0-	0.56		
V		5°			



47/

TO-92 ammopack shipment (suffix"-AP") mechanical data

Dim.	mm				
Dim.	Min	Тур	Max		
A1			4.80		
T			3.80		
T1			1.60		
T2			2.30		
d			0.48		
P0	12.50	12.70	12.90		
P2	5.65	6.35	7.05		
F1,F2	2.44	2.54	2.94		
F3	4.98	5.08	543		
delta H	-2.00		2.70		
W	17.50	18.00	19.00		
W0	5.70	6.00	6.30		
W1	8.50	9.00 9.25			
W2			0.50		
Н	18.50	10	20.50		
H3	0.5		1.5		
H0	15.50	16 00	16.50		
H1			25.00		
D0	3.80	4.00	4.20		
t		10	0.90		
L			11.00		
I1	3.00				
delta P	-1.00		1.00		



STX690A Revision history

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
09-Feb-2009	1	Initial release.

Obsolete Producits). Obsolete Producits)

9/10

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its stibs. Then its ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and ser the described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be doesned an cense grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND CALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZE REPRESENTATIVE OF ST, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZEL OF WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS, WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY CALLY SE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale (fS products with provisions different from the statements and/or technical features set forth in this document shall immediately void any and antique and shall not create or extend in any manner whatsoever, any ability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

577